

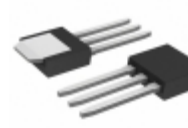


	<h2 style="color: red;">NTD6415ANLT4G</h2>
	<p>Hersteller-Teilenummer: NTD6415ANLT4G</p> <p>Hersteller / Marke: AMI Semiconductor / ON Semiconductor</p> <p>Teil der Beschreibung: MOSFET N-CH 100V 23A DPAK</p> <p>Datenblätter:  NTD6415ANLT4G.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 100973 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	NTD6415ANLT4G
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET N-CH 100V 23A DPAK
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	100973 pcs Stock
Serie	-
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 175°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-252-3, DPak (2 Leads + Tab), SC-63
Supplier Device-Gehäuse	DPAK
Verlustleistung (max)	83W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	100V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	23A (Tc)
Rds On (Max) @ Id, Vgs	52 mOhm @ 10A, 10V
VGS (th) (Max) @ Id	2V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	35nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	1024pF @ 25V
Antriebsspannung (Max Rds On, Min Rds On)	4.5V, 10V
Vgs (Max)	±20V
Verpackung	Tape & Reel (TR)



















































NTD6415ANLT4G ist neu im Original, Suche NTD6415ANLT4G Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie NTD6415ANLT4G AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage NTD6415ANLT4G: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>NTD6414ANT4G AMI Semiconductor / ON Semiconductor MOSFET N-CH 100V 32A DPAK</p>	 <p>NTD6416AN-1G AMI Semiconductor / ON Semiconductor MOSFET N-CH 100V 17A IPAK</p>	 <p>NTD6415AN-1G AMI Semiconductor / ON Semiconductor MOSFET N-CH 100V 23A IPAK</p>	 <p>NTD6414AUG ON NTD6414AUG ON</p>
 <p>NTD6416ANL ON NTD6416ANL ON</p>	 <p>NTD6415AN ON NTD6415AN ON</p>	 <p>NTD6416AN ON NTD6416AN ON</p>	 <p>NTD6415ANL ON NTD6415ANL ON</p>

heiße Teile

Mehr

 NTD5867NLT4G	 NTD5867NT4G	 NTD60N02KG	 D NTD60N02R	 NTD60N02R-001
 NTD60N02R-032	 NTD60N02R-035	 D NTD60N02R-1G	 NTD60N02R-1R	 NTD60N02R-35G
 NTD60N02RG	 NTD60N02RG-1G	 NTD60N02RT	 NTD60N02RT4	 NTD60N02RT4G
 D NTD60N03RT4G	 NTD60N03T4	 NTD60N03T4G	 NTD6414AN	 NTD6414AN-1G
 NTD6414ANT4G	 NTD6414AUG	 NTD6415AN	 NTD6415AN-1G	 NTD6415ANL
 NTD6415ANT4G	 NTD6416AN	 D NTD6416AN-1G	 NTD6416ANG	 NTD6416ANL
 NTD6416ANL-1G	 D NTD6416ANLT4G	 NTD6416ANT4G	 NTD65N03G	 NTD65N03R-001
 NTD65N03R-035	 NTD65N03R-1G	 NTD65N03R-35G	 NTD65N03RG	 NTD65N03RT4G
 NTD6600G	 NTD6600N	 NTD6600N-001	 D NTD6600N-1G	 NTD6600NT4
 NTD6600NT4G	 NTD70N03	 NTD70N03R	 NTD70N03R-001	 NTD70N03R-1

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